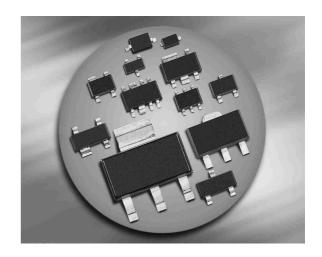


# Silicon RF Switching Diode

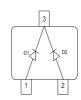
- Low-loss VHF / UHF switch above 10 MHz
- PIN diode with low forward resistance
- Pb-free (RoHS compliant) package





### BAT18-04 BAT18-05





Туре	Package	Configuration	<b>L</b> <sub>S</sub> (nH)	Marking
BAT18-04	SOT23	series	1.8	AUs
BAT18-05	SOT23	common cathode	1.8	ASs

**Maximum Ratings** at  $T_A = 25$ °C, unless otherwise specified

Parameter	Symbol	Value	Unit
Diode reverse voltage	$V_{R}$	35	V
Forward current	I <sub>F</sub>	100	mA
Junction temperature	$T_{i}$	150	°C
Operating temperature range	$T_{op}$	-55 125	
Storage temperature	$T_{ m stg}$	-55 150	

### **Thermal Resistance**

Parameter	Symbol	Value	Unit
Junction - soldering point <sup>1)</sup>	R <sub>thJS</sub>	≤ 290	K/W
BAT18-04, BAT18-05			

 $<sup>^{1}</sup>$ For calculation of  $R_{\mathrm{thJA}}$  please refer to Application Note Thermal Resistance



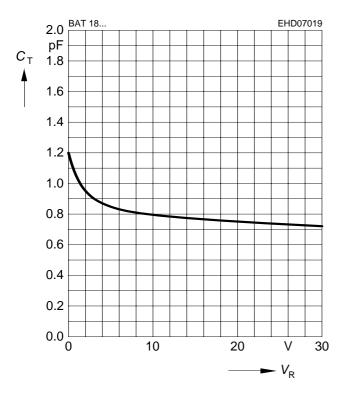
**Electrical Characteristics** at  $T_A = 25$ °C, unless otherwise specified

Parameter	Symbol		Values		
		min.	typ.	max.	]
DC Characteristics		•			
Reverse current	$I_{R}$				nA
V <sub>R</sub> = 20 V		-	-	20	
$V_{R}$ = 20 V, $T_{A}$ = 60 °C		-	-	200	
Forward voltage	$V_{F}$	-	0.92	1.2	V
<i>I</i> <sub>F</sub> = 100 mA					
AC Characteristics					
Diode capacitance	C <sub>T</sub>	-	0.75	1	pF
$V_{R} = 20 \text{ V}, f = 1 \text{ MHz}$					
Forward resistance	$r_{f}$	-	0.4	0.7	Ω
$I_{\rm F}$ = 5 mA, $f$ = 100 MHz					
Charge carrier life time	τ <sub>rr</sub>	-	120	-	ns
$I_{\rm F}$ = 10 mA, $I_{\rm R}$ = 6 mA, measured at $I_{\rm R}$ = 3 mA ,					
$R_{L}$ = 100 $\Omega$					
I-region width	$W_{I}$	-	3	-	μm



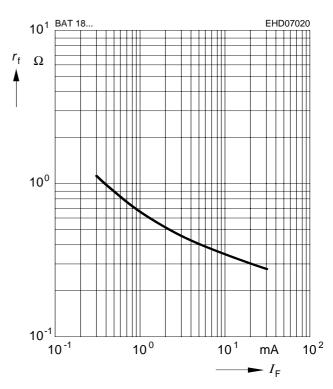
# Diode capacitance $C_T = f(V_R)$

f = 1MHz



# Forward resistance $r_f = f(I_F)$

f = 100MHz

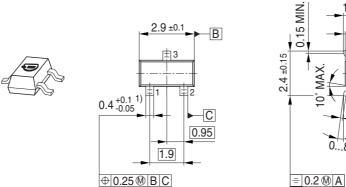


1±0.1 0.1 MAX.

0.08...0.15

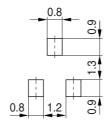


### Package Outline

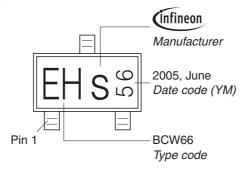


1) Lead width can be 0.6 max. in dambar area

### Foot Print

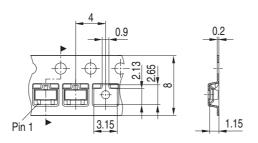


### Marking Layout (Example)



### Standard Packing

Reel ø180 mm = 3.000 Pieces/Reel Reel ø330 mm = 10.000 Pieces/Reel





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